

MCSO1ES High Stability

High Temp Clock Oscillator 15 kHz – 100 MHz

NCSOTES NCSOTES Lead-free



APPLICATIONS

Security / Safety Avionics / Aerospace Radio Communication Geothermal Equipment Remote Control / Telemetry Down Hole and Well Drilling

DESCRIPTION

The MCSO1ES is a High Temperature, High Frequency SMD Oscillator that incorporates an integrated HCMOS circuit and an SC-Cut XTAL. It operates under vacuum in a hermetically sealed ceramic package.

FEATURES

Outstanding hermetic sealing with gold-tin preform. High stability and low aging guaranteed by hermetic sealing. Frequency stability guaranteed for 1000 h at T_{MAX}. Very fast start-up. Operates in fundamental mode. High shock and vibration resistant. 100% Pb-free, RoHS-compliant.

ELECTRICAL CHARACTERISTICS AT 25°C

Overall frequency stability over 1)temperature range $R = -10$ to $+150^{\circ}C$ $S = -10$ to $+175^{\circ}C$ $T = -10$ to $+210^{\circ}C$ 2)	ΔF/F	≤ ±50 ≤ ±100 ≤ ±150	ppm
Supply voltage ±5% 3)	V _{DD}	2.5 / 3.3 / 5.0	V
Input current	I _{DD}	See I _{DD} table	
Output signal		HCMOS compatible	
F _{OUT} duty cycle @ V _{DD} /2 (min./max.)	δ _{FOUT}	40 / 60	%
Rise & fall time, \leq 30 MHz For L version, t _r / t _f \leq 25 ns (C _L = 15 pF, 20% to 80% V _{DD})	t _r / t _f	≤ 7	ns
Rise & fall time, > 30 MHz (C _L = 15 pF, 10% to 90% V _{DD})	t _r / t _f	≤ 3	ns
Output level V _{OL} / V _{OH}		< 0.4 / > V _{DD} -0.5	V
Start-up time	t _{START}	< 5	ms
Capacitive load min. / max. For L version, C_L max. = 27 pF	CL	3 / 47	pF

Including adjustment at +25°C, long term aging 1000 h at T_{MAX}, V_{DD} variations ±5% and C_L variations min. to max.

2) For the low consumption version (L), T version is only available as 5.0 V version and the T range is limited to +200 $^\circ C$

3) A 47 nF decoupling capacitor has to be connected between $V_{\mbox{\scriptsize DD}}$ and GND

INPUT	CURF	RENT:	I_{DD} (no	load)
(Early	orcion	c = 10		

(For L version, C_L = 10 pF)

Frequency	32.768 kHz (L)	≤ 10 MHz	≤ 30 MHz	> 30 to 100 MHz
V _{DD} = 2.5 V (W)	< 100 µA	< 2 mA	< 3 mA	< 15 mA
V _{DD} = 3.3 V (V)	< 110 µA	< 4 mA	< 5 mA	< 20 mA
V_{DD} = 5.0 V (Blank)	< 120 µA	< 6 mA	< 7 mA	< 30 mA

STANDARD FREQUENCIES

ENABLE/DISABLE E/D, OPTION 1

Frequencies				
32.768 kHz	20.0000 MHz	24.5760 MHz		
L version: Other frequencies from 15 kHz to 100 kHz on request				
Standard version: Other frequencies from 100 kHz to 100 MHz on request				

	1		
Reaction time, L version	t	< 5	ms
Reaction time, Standard version	t	< 1	μs
Input level V _{IL} / V _{IH}		$< 0.3 V_{DD} / > 0.7 V_{DD}$	V

Pin 1 E/D	Pin 3 F _{out}
V _{IH} or open	Output enabled
V _{IL}	Output disabled (Hi-Z)
No E/D function before V/ is not	

No E/D function before V_{DD} is set.

ENVIRONMENTAL CHARACTERISTICS

	Conditions
Storage temperature range	–65 to +125°C
Shock resistance (survival)	10000 g, 0.3 ms, ½ sine
Vibration resistance (survival)	80 g / 10 – 2000 Hz

TERMINATIONS AND				
PROCESSING, OPTION 2				

Reflow per IPC/JEDEC J-STD-020C	260°C / 20 - 40 s	
Package	Ceramic	
Lid	Ceramic lid (C)	
Lid	Kovar lid (Blank)	
Terminations (Option 2)	SnAgCu solder dipped pads (T3)	
(T3 not available for T range)	Au flashed pads (Blank)	

ORDERING INFORMATION

MCSO1ES	c v - s	40.000 MHz	E/D	<u>T3</u>	xxx
L = Low power Blank = Standard C = Ceramic lid Blank = Kovar lid		Frequency Option 1 E/D = Enable/I Blank = No funct	Disable		
$W = V_{DD} = 2.5 V$ $V = V_{DD} = 3.3 V$ $Blank = V_{DD} = 5.0 V$		T3 = SnAgCu Blank = Au flash Customer speci	ı solder d ed pads fication l	ipped pa	ds **
Temperature range Customer specification N ² R = -10 to +150°C S = -10 to +175°C T = -10 to +210°C * X = Custom X = Custom </th					
A unique part number will be generated for each product specification, i.e:					
20xxxx-ML00 ≥	250 pcs (in 16	6 mm tape on 7" r	eel)		
20xxxx-EA00	yyy pcs (in E	SD plastic tray)			

All specifications subject to change without notice.



Micro Crystal AG Muehlestrasse 14 CH-2540 Grenchen Switzerland Phone +41 32 655 82 82 sales@microcrystal.com www.microcrystal.com